

YG911S2R

(200V / 5A TO-220F15)

LOW LOSS SUPER HIGH SPEED DIODE

■ Features

- Low VF
- Super high speed switching.
- High reliability by planer design.

■ Applications

- High speed power switching.

■ Maximum Ratings and Characteristics

- Absolute Maximum Ratings

Item	Symbol	Conditions	Rating	Unit
Repetitive peak reverse voltage	V _{RRM}		200	V
Repetitive peak surge reverse voltage	V _{RSM}		200	V
Isolation voltage	V _{iso}	Terminals to Case, AC. 1min.	1500	V
Average output current	I _O	duty=1/2, T _c =134°C Rectangl wave	5	A
Surge current	I _{FSM}	Sine wave 10ms	50	A
Operating junction temperature	T _j		-40 to +150	°C
Storage temperature	T _{stg}		-40 to +150	°C

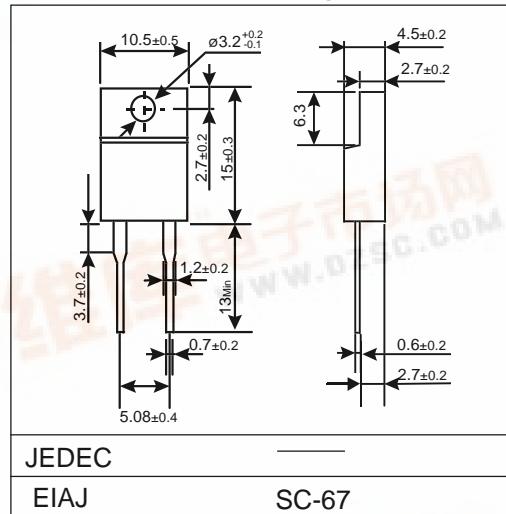
- Electrical Characteristics (T_a=25°C Unless otherwise specified)

Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V _F	I _F =5.0A	0.95	V
Reverse current	I _R	V _R =V _{RRM}	100	μA
Reverse recovery time	t _{rr}	I _F =0.1A,I _R =0.2A,I _{rec} =0.05A	35	ns
Thermal resistance	R _{th(j-c)}	Junction to case	5.0	°C/W

• Mechanical Characteristics

Mounting torque	Recommended torque	0.3 to 0.5	N · m

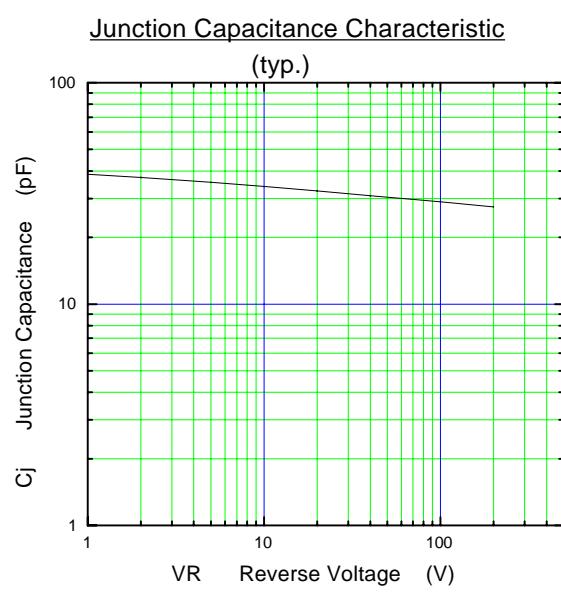
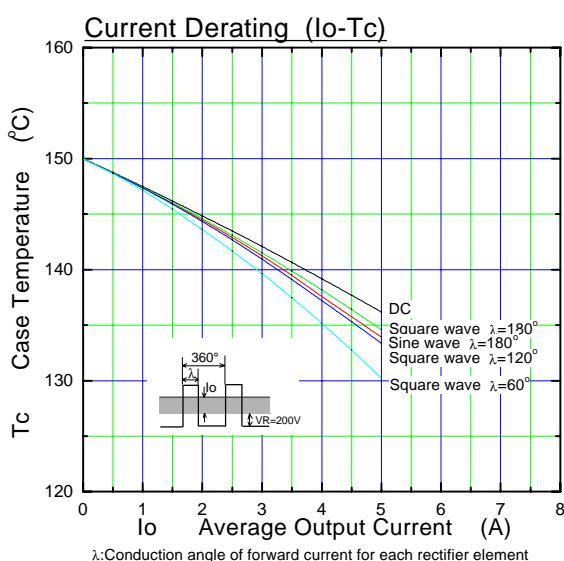
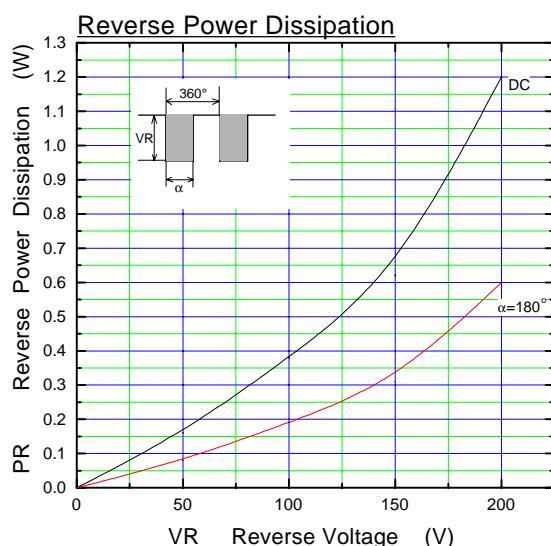
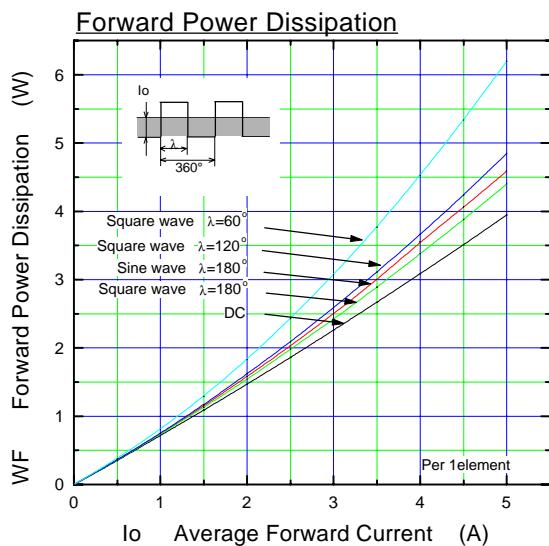
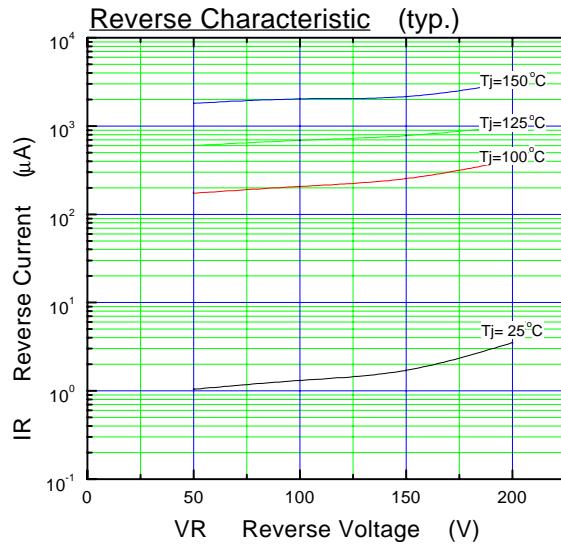
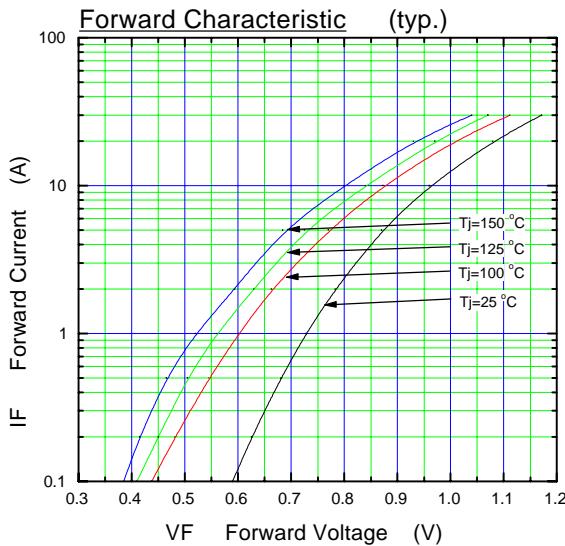
■ Outline Drawings



■ Connection Diagram



■ Characteristics



(200V / 5A TO-22OF15)

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